

SANYO**FC806**

Silicon Schottky Barrier Diode

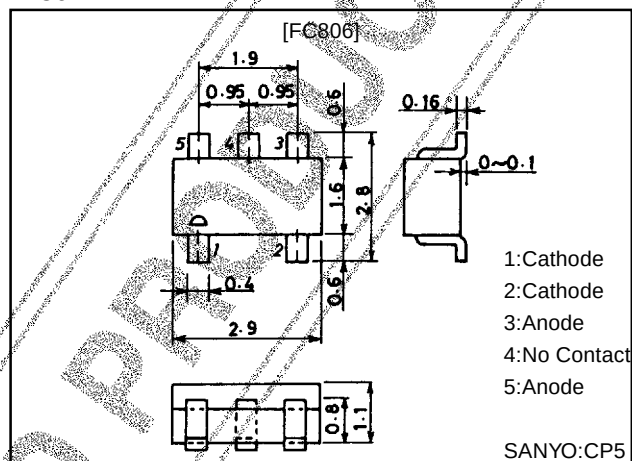
50V, 100mA Rectifier**Features**

- Low forward voltage (V_F max=0.55V) .
- Fast reverse recovery time (t_{rr} max=10ns) .
- Composite type with 2 diodes contained in the CP package currently in use, saving the mounting space greatly.
- The FC806 is formed with two chips, each being equivalent to the SB01-05CP, placed in one package.

Package Dimensions

unit:mm

1236A

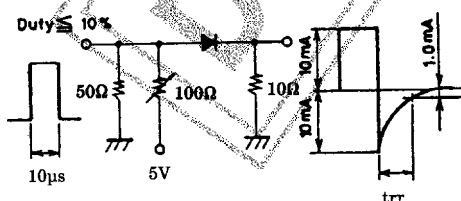
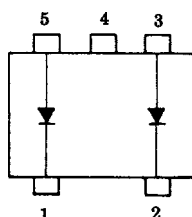
**Specifications****Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$**

Parameter	Symbol	Conditions	Ratings	Unit
Repetitive Peak Reverse Voltage	V_{RRM}		50	V
Nonrepetitive Peak Reverse Surge Voltage	V_{RSM}		55	V
Average Output Current	I_O		100	mA
Surge Forward Current	I_{FSM}	50MHz sine wave, 1 cycle	2	A
Junction Temperature	T_J		-55 to +125	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +125	$^\circ\text{C}$

Electrical Characteristics at $T_a = 25^\circ\text{C}$

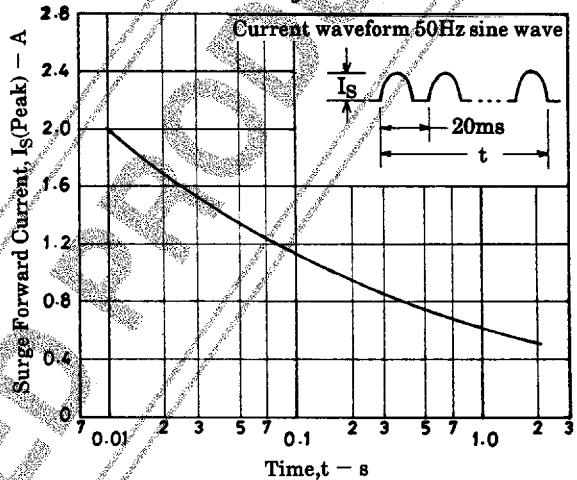
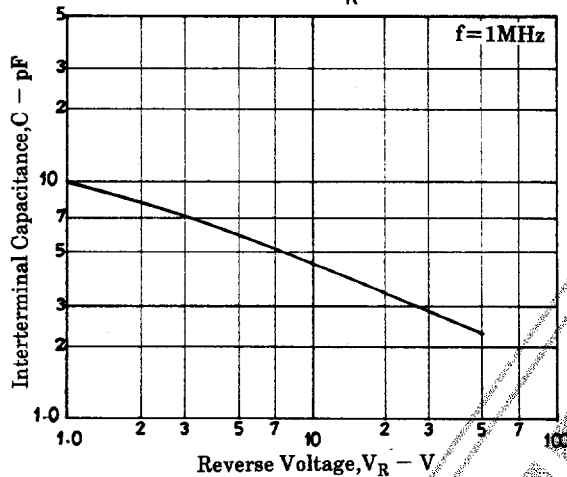
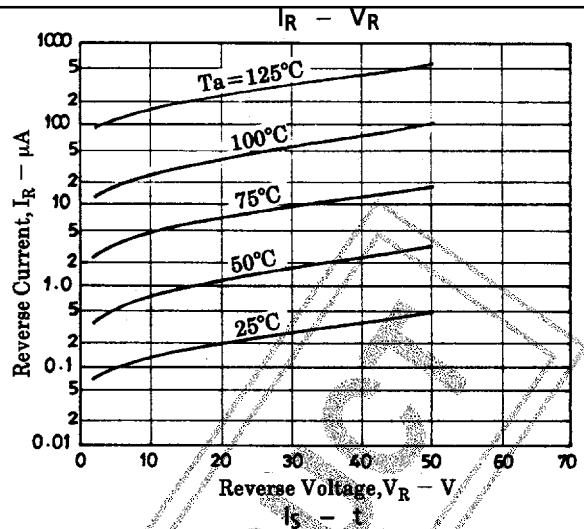
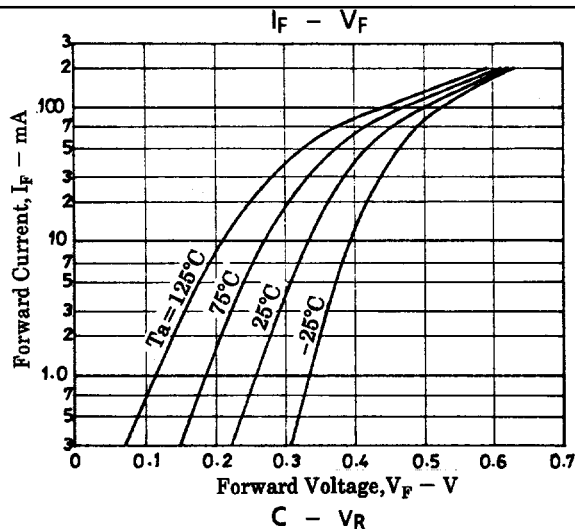
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Reverse Voltage	V_R	$I_R=50\mu\text{A}$	50			V
Forward Voltage	V_F	$I_F=100\text{mA}$			0.55	V
Reverse Current	I_R	$V_R=25\text{V}$			15	μA
Interterminal Capacitance	C	$V_R=10\text{V}$, $f=1\text{MHz}$		4.4		pF
Reverse Recovery Time	t_{rr}	$I_F=I_R=100\text{mA}$, See specified Test Circuit			10	ns
Thermal Resistance	$R_{th} (j-a)$			560		$^\circ\text{C/W}$

• Marking:806

 t_{rr} Test Circuit**Electrical Connection****SANYO Electric Co.,Ltd. Semiconductor Business Headquarters**

TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

22898HA (KT)/O3196GI/8030MH, TA, TS No.3401-1/2



■ No products described or contained herein are intended for use in surgical implants, life-support systems, aerospace equipment, nuclear power control systems, vehicles, disaster/crime-prevention equipment and the like, the failure of which may directly or indirectly cause injury, death or property loss.

■ Anyone purchasing any products described or contained herein for an above-mentioned use shall:

- ① Accept full responsibility and indemnify and defend SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors and all their officers and employees, jointly and severally, against any and all claims and litigation and all damages, cost and expenses associated with such use;
- ② Not impose any responsibility for any fault or negligence which may be cited in any such claim or litigation on SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors or any of their officers and employees jointly or severally.

■ Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. SANYO believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.

This catalog provides information as of February, 1998. Specifications and information herein are subject to change without notice.